

Notice of References Cited	Application/Control No. 10/550,860		Applicant(s)/Patent Under Reexamination MUCCINI ET AL.	
	Examiner MATTHEW W. SUCH		Art Unit 2891	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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*	B	US-5,596,208	01-1997	Dodabalapur et al.	257/66
*	C	US-2006/0043380	03-2006	Hiroshi et al.	257/079
*	D	US-2003/0122120	07-2003	Brazis et al.	257/40
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*	N	WO 03071608 A1	08-2003	World Intellect	HIROSHI K et al.	
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NON-PATENT DOCUMENTS

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*	U	Rogers, J.A., et al. "Low-Voltage 0.1 micron Organic Transistors and Complementary Inverter Circuits Fabricated With a Low-Cost Form of Near-Field Photolithography." APPL. PHYS. LETT., Vol. 75, No. 7 (16 August 1999): pp. 1010-1012.			
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	W	Horowitz, G., et al. "Photoinduced Spontaneous and Stimulated Emission in Sexithiophene Single Crystals." OPT. MATER., Vol. 9 (January 1998): pp. 46-52.			
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.